

VT6Z1T2R

Request a Quote

VT6Z1T2R Information



For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



VT6Z1T2R Specifications

Manufacturer Part Number	VT6Z1T2R
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	6-SMD
Series	-
Transistor Type	NPN, PNP
Current - Collector (Ic) (Max)	200mA
Voltage - Collector Emitter Breakdown (Max)	20V
Vce Saturation (Max) @ Ib, Ic	300mV @ 10mA, 100mA
Current - Collector Cutoff (Max)	100µA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	120 @ 1mA, 2V
Power - Max	150mW
Frequency - Transition	400MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	6-SMD
Supplier Device Package	VMT6
	Report errors?

E-mail: salesdept@heisener.com

VT6Z1T2R Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about VT6Z1T2R, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com